

12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN# 20130730000 Alternate Assembly Site Qualification Change Notification / Sample Request

Date: 8/2/2013

To: Newark/Farnell PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (PCN www admin team@list.ti.com).

Sincerely,

PCN Team SC Business Services Phone: +1(214) 480-6037 Fax: +1(214) 480-6659

Texas Instruments, Inc.

20130730000 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICETPD12S521DBTR

CUSTOMER PART NUMBER

null

Technical details of this Product Change follow on the next page(s).

PCN Number:		20130730000					PCN Date:		08/02/2013	
Title:	Alternate Ass	embly	/ Site Qua	lificatio	n					
Customer Contact:		PCN A	PCN Manager		e:	+1(214)480-6037		Dept:	t: Quality Services	
Proposed 1 st Ship Da		te:	11/02/2013 Es		timated Samp	Availability: 09/02		09/02/2013		
Change	Type:									
Assembly Site			Asseml	Assembly Process				Assembly Materials		
Design			Electric	Electrical Specification				Mechanical Specification		
Test Site			Packing	Packing/Shipping/Labeling				Test Process		
Wafer Bump Site			Wafer I	Wafer Bump Material			Wafer Bump Process			
Waf	er Fab Site		Wafer Fab Materials				Wafer Fab Process			
PCN Details										

Description of Change:

Qualification of TI Taiwan and TI Malaysia as an alternate Assembly sites for select devices as shown below. The material set will remain unchanged for both groups.

Reason for Change:

Continuous Customer Supply

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Changes to product identification resulting from this PCN:

Group 1

Assembly Site		
TI Malaysia	Assembly Site Origin (22L)	ASO: MLA
TI Taiwan	Assembly Site Origin (22L)	ASO: TAI

Group 2

Assembly Site		
TI Clark (Philippines)	Assembly Site Origin (22L)	ASO: QAB
TI Malaysia	Assembly Site Origin (22L)	ASO: MLA

Sample product shipping label (not actual product label)



LBL: 5A (L)T0:1750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483\$I2 (P) (2P) REV: (V) 0033317 (20L) C\$0: SHE (21L) CCO:USA (22L) A\$0: MLA (23L) ACO: MY\$

Topside Device marking:

Assembly site code for TI Clark = I Assembly site code for TI Malaysia = K Assembly site code for TI Taiwan = T

Product Affected:									
Group 1: Adding TI Taiwan									
HPA00694DBTR	HPA00954DBTR	TPD12S521DBTR/2354	TPD12S521DBTRG4						
HPA00885DBTR	TPD12S521DBTR								
Group 2: Adding TI Malaysia									
TXS02326AMRGER									

TI Taiwan Qualification Data: Approved July 2013								
This qualification has been specifically developed for the validation of this change. The qualification data								
validates that the proposed chan	validates that the proposed change meets the applicable released technical specifications.							
Qualification Device: TPD12S521DBTR (MSL2-260C)								
Package Construction Details								
Assembly Site:	TAI	Mold Compound:	4206193					
# Pins-Designator, Family:	38-DBT, TSSOP	Mount Compound:	4042500					
Lead Finish:	NiPdAu, Cu	Bond Wire:	0.96 Mil Dia., Cu					
Qualification: Plan Test Results								
Reliability Test	Conditions	Sample Size / Fail						
Electrical Characterization	Per PDS range	Pass						
X-ray	(top side only)	Pass						

TI Taiwan Refere	nce	Qualification	n Data: Approv	ed	Janı	uary 20	800
This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.							
Qualification Device: BQ8015DBT (MSL 2-260c)							
Package Construction Details							
Assembly Site: TAI			Mold Compou	nd:	4206193		
# Pins-Designator, Family:	38-I	DBT, TSSOP	Mount Compound		4042500		
Leadframe (Finish, Base):	NiPo	dAu, Cu	Cu Bond Wii		0.96 Mil Dia., Cu		
Qualification: Plan Test Results							
Reliability Test		Conditions			Sample Size /		/ Fail
Reliability Test		Conditions			ot 1	Lot 2	Lot 3
**High Temp Operating Lif	fe	155C (240 Hrs)			0/0	40/0	40/0
**High Temp. Storage Bak	кe	170C (420 Hrs)		7	7/0	77/0	77/0
**Biased HAST		130C/85%RH (96 Hrs)			0/0	40/0	40/0
**Autoclave 121C		121C, 2 ATM (96 Hrs)			7/0	77/0	77/0
**T/C -65C/150C		-65C/+150C (500 Cyc)			7/0	77/0	77/0
**Thermal Shock		-65C/+150C (500 Cyc) 77/0 77/0 7			77/0		
Notes: **Tests received pr	ecor	nditioning seque	nce: MSL2-260C				

TI Malaysia Qualification Data: Approved July 2013 This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications. **Qualification Device: TXS02326AMRGER** (MSL2-260C) **Package Construction Details** 4208625 Assembly Site: Mold Compound: MLA # Pins-Designator, Family: 24-RGE, VQFN Mount Compound: 4205846 Lead Finish: NiPdAu, Cu Bond Wire: 0.96 Mil Dia., Cu Qualification: Plan X Test Results Reliability Test Conditions Sample Size / Fail Electrical Characterization Per PDS range Pass X-ray (top side only) Pass

TI Malaysia Reference Qualification Data: Approved March 2007								
This qualification has been specifically developed for the validation of this change. The qualification data								
validates that the proposed ch	validates that the proposed change meets the applicable released technical specifications.							
Qualification Device: TSC2200RHB (MSL 2-260c)								
Package Construction Details								
Assembly Site:	MLA	1	Mold Compou	nd:	4208	3625		
# Pins-Designator, Family: 24-F		RGE, VQFN	Mount Compou	Mount Compound:		4205846		
Leadframe (Finish, Base): NiPo		IAu, Cu	Bond W	Bond Wire:		0.96 Mil Dia., Cu		
Qualification: Plan Test Results								
Reliability Test		Conditions			Sam	ple Size /	′ Fail	
Reliability Test		Conditions		Lo	ot 1	Lot 2	Lot 3	
**Steady-state Life Test		150C (168, 300 Hrs)		11	16/0	116/0	116/0	
**High Temp. Storage Bake		150C (1000 Hrs)		7	7/0	77/0	77/0	
**Biased HAST		130C/85%RH (96 Hrs)		40/0		40/0	40/0	
**Autoclave 121C		121C, 2 ATM (96 Hrs)		7	7/0	77/0	77/0	
**T/C -65C/150C		-65C/+150C (500 Cyc)		7	7/0	77/0	77/0	
Notes: **Tests received preconditioning sequence: MSL2-260C								

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com